Features：

- Isolated mounting base 2500V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving

Typical Applications

- Various rectifiers
- DC supply for PWM inverter

V_{RSM}	V_{RRM}	Type & Outline
900V	800V	MDx380-08-413F3D
1100V	1000V	MDx380-10-413F3D
1300V	1200V	MDx380-12-413F3D
1500V	1400V	MDx380-14-413F3D
1700V	1600V	MDx380-16-413F3D
1900V	1800V	MDx380-18-413F3D

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_j(℃)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled, T_C=100℃	150			380	A
$I_{F(RMS)}$	RMS forward current		150			596.6	A
I_{RRM}	Repetitive peak current	at V_{RRM}	150			30	mA
I_{FSM}	Surge forward current	10ms half sine wave V_R=0.6V_{RRM}	150			9.5	kA
I^2t	I^2t for fusing coordination					451.25	A^2s*10^3
V_{FO}	Threshold voltage		150			0.72	V
r_F	Forward slope resistance					0.40	mΩ
V_{FM}	Peak forward voltage	I_{FM}=1100A	25			1.40	V
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180° sine, Single side cooled per chip				0.12	℃/W
$R_{th(c-h)}$	Thermal resistance case to heatsink	At 180°sine, Single side cooled per chip				0.04	℃/W
V_{iso}	Isolation voltage	50Hz,R.M.S,t=1min,I_{iso}:1mA(max)		2500			V
F_m	Terminal connection torque(M8)				12.0		N·m
	Mounting torque(M6)				6.0		N·m
T_{vj}	Junction temperature			-40		150	℃
T_{stg}	Stored temperature			-40		125	℃
W_t	Weight				810		g
Outline	413F3D						

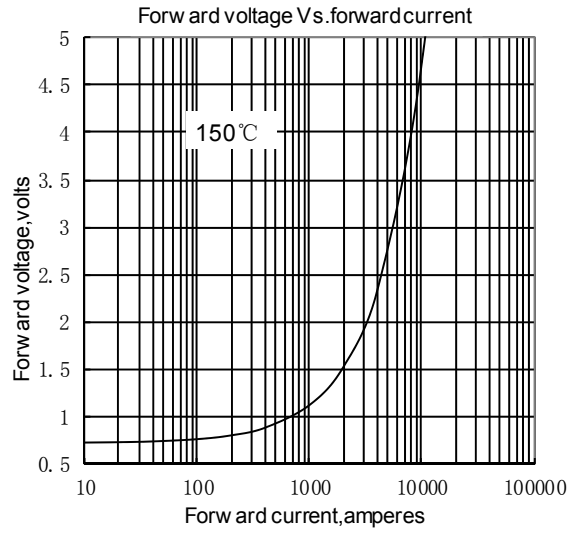

Fig.1

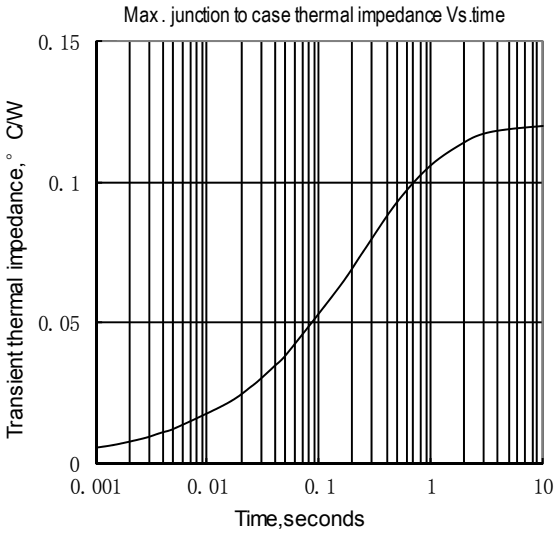

Fig.2

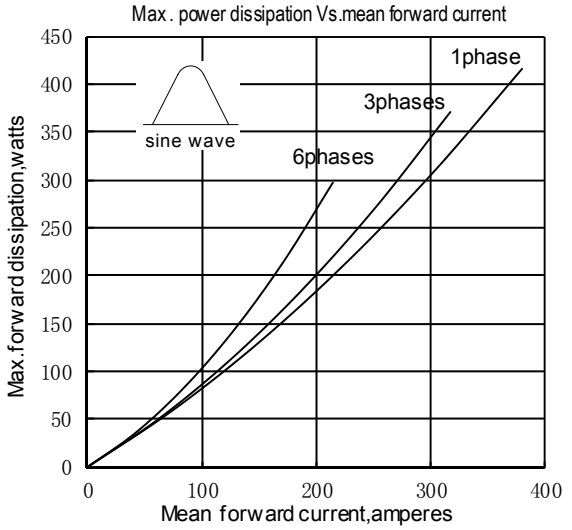

Fig.3

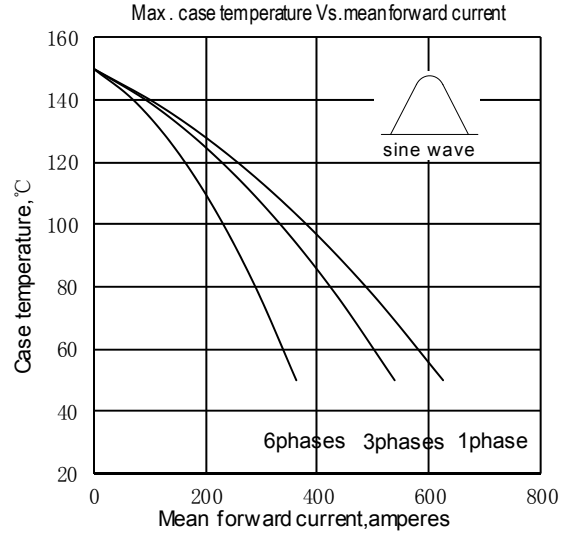

Fig.4

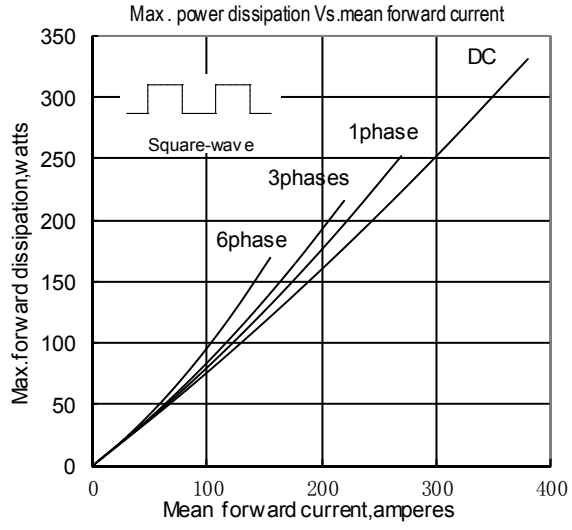

Fig.5

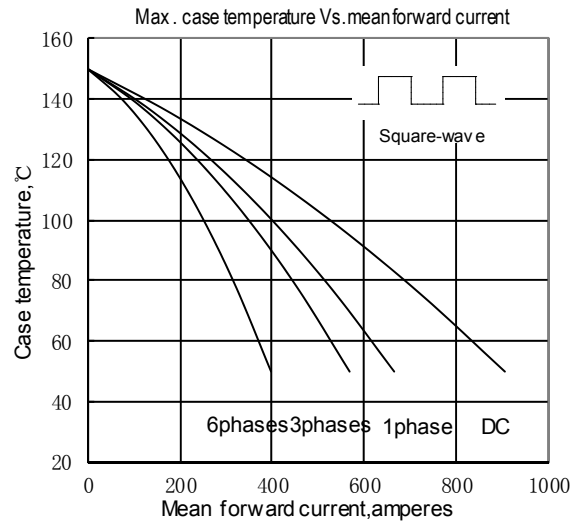

Fig.6

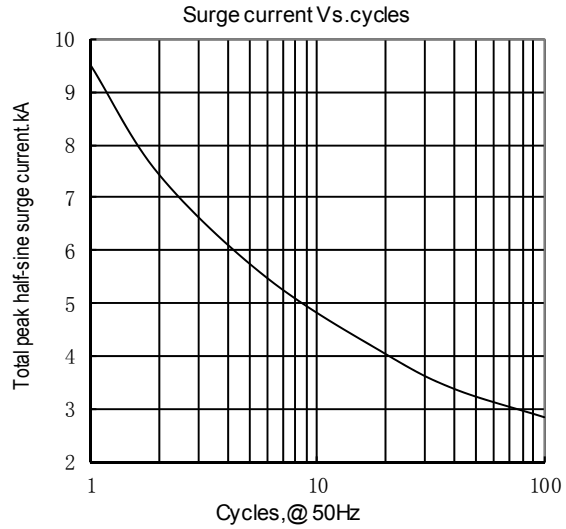

Fig.7

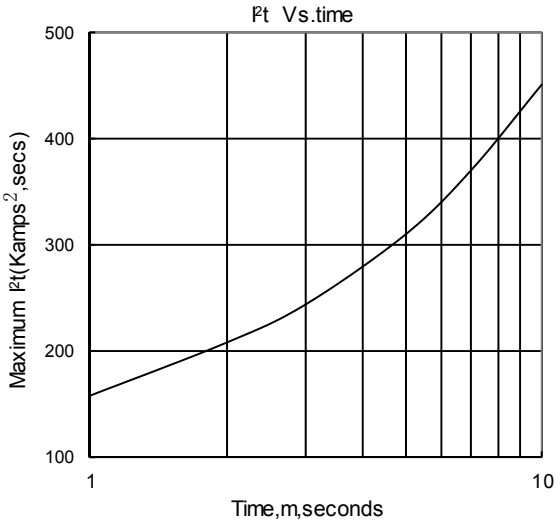

Fig.8

Outline: